Supplementary Information

## Ultrahigh-sensitive optical temperature sensing based on quasi-thermalized green emissions from Er:ZnO

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**Figure S1**. (a) FESEM image of Er:ZnO micro rods for Er-0.005 and (b) corresponding EDX spectrum representing presence of Zn, O and Er in the sample.



**Figure S2**. (a–d) High resolution XPS spectra of Er–4d of Er:ZnO sample for different Er doping content (0.001, 0.003, 0.004, 0.005) respectively.



Figure S3. Room temperature PL spectra of Eu:ZnO with 355 nm excitation for different Er doping content.



**Figure S4**. Variation of 540 nm peak intensity with temperature in the 83-553 K range for the Er-0.002 sample.



**Figure S5**. Variation of sensitivity (relative (a) and absolute (b)) for green intensity ratio with applied temperature.



**Figure S6**. (a) Variation of 565 and 663 nm integral peak intensity with temperature and (b) corresponding intensity ratio variation with temperature.



**Figure S7**. Plot for variation of different integral peak intensities with Er doping amount at room temperature.



**Figure S8**. Time resolved PL for (a) ZnO and (b) ErZnO (for Er-4%) with excitation and detection wavelength respectively at 469 nm 520 nm for both the cases. The curves are fitted to double exponential functions and the average life time is obtained as 0.232 ns and 0.143 ns respectively for ZnO and ErZnO.

The population transfer efficiency can be obtained by following equation

$$\eta = 1 - \tau / \tau_0$$

where  $\tau$  and  $\tau_0$  represents average life time of ErZnO and ZnO respectively. The value of  $\eta$  is found to be 38.4% for the 4% Er doped ZnO sample (as it the maximum intense one).



**Figure S9.** Variation of green intensity ratio with temperature in logarithmic scale. The linear part is fitted to  $\ln I_{540}/I_{565}$ =6.65-3053/*T* and the deviation increases at lower temperature. This suggests that the degree of population ( $\eta$ ) is equal to 1 at higher temperature, which is only due to the thermal population process,<sup>1</sup> and  $\eta < 1$  at lower temperature.<sup>1</sup>

| Er    | Temp range (K) | Maximum                 | Temperature for            |
|-------|----------------|-------------------------|----------------------------|
|       |                | $S_A (\mathrm{K}^{-1})$ | maximum S <sub>A</sub> (K) |
| 0.001 | 83 - 493       | 2.127x10-2              | 493                        |
| 0.002 | 83 - 493       | 2.435×10-2              | 493                        |
| 0.003 | 83 - 493       | 1.774x10-2              | 493                        |
| 0.004 | 83 - 493       | 1.756x10-2              | 493                        |
| 0.005 | 83 - 493       | 1.413x10-2              | 493                        |

Table S1. Comparison of maximum  $S_{\rm A}$  values for 540 and 565 nm intensity ratio.

**Table S2**. Comparison of  $\Delta E$  and  $S_R$  of different Er:ZnO microrods for  $I_{663}/I_{565}$ . Theoretical  $\Delta E$  is 2616.2 cm<sup>-1</sup>. T<sub>max</sub> is the temperature corresponds to maximum S<sub>A</sub> value.

| Er    | Temp range (K) | Maximum $S_A(K^{-1})$  | $ximum S_A(K^{-1}) \Delta E(cm^{-1})$ |                            |
|-------|----------------|------------------------|---------------------------------------|----------------------------|
|       |                | (T <sub>max</sub> , K) |                                       | $(S_R)$ (K <sup>-1</sup> ) |
| 0.001 | 83 - 493       | 2.976x10-2 (83)        | 1414                                  | $2034/T^{2}$               |
| 0.002 | 83 - 493       | 7.314x10-2 (83)        | 1638                                  | $2357/T^2$                 |
| 0.003 | 83 - 493       | 6.555x10-2 (83)        | 1170                                  | $1683/T^2$                 |
| 0.004 | 83 - 493       | 5.561x10-2 (83)        | 1384                                  | $1991/T^2$                 |
| 0.005 | 83 - 493       | 7.539x10-2 (83)        | 997                                   | $1434/T^2$                 |

| Host Materials  | Excitations | Temperature | $\Delta E ( cm^{-1} )$ | $\Delta E (cm^{-1})$ | $\Delta E_e / \Delta E_t$ | ΔE/k ( K)      | References |
|---|-------------|-------------|------------------------|----------------------|---------------------------|----------------|------------|
|   | (nm)        | range (K)   | (Theoretical)          | (Experimental)       |                           | (experimental) |            |
| Er3+ Si-B-Ba-   | 978         | 297-673     | 512                    | 233                  | 0.4550                    | 335            | 2          |
| Na glass  |             |             |                        |                      |                           |                |            |
| Er3+ PLZT   | 980         | 310-883     | 1027                   | 773                  | 0.7526                    | 1112           | 3          |
| ceramics  |             |             |                        |                      |                           |                |            |
| Er3+, Mo6+  | 976         | 295-973     | 842                    | 901                  | 1.0701                    | 1296           | 4          |
| :YbAG   |             |             |                        |                      |                           |                |            |
| Er3+, Yb3+:β-   | 980         | 303-523     | 2830.6                 | 266.8                | 0.0943                    | 384            | 5          |
| NaLuF4  |             |             |                        |                      |                           |                |            |
| Er3+, Yb3+,   | 980         | 301-403     | 972                    | 474                  | 0.4877                    | 682            | 6          |
| Eu3+ :Y2O3  |             |             |                        |                      |                           |                |            |
| Er3+, Yb3+  | 980         | 300-485     | 1033                   | 538                  | 0.5208                    | 774            | 7          |
| :YVO4   |             |             |                        |                      |                           |                |            |
| Er3+, Yb3+  | 980         | 93-613      | 866                    | 575                  | 0.6639                    | 827            | 8          |
| :NaBiTiO3   |             |             |                        |                      |                           |                |            |
| ceramics  |             |             |                        |                      |                           |                |            |
| Er3+, Yb3+  | 980         | 285-453     | 686                    | 860                  | 1.2536                    | 1250           | 9          |
| :LiNbO3   |             |             |                        |                      |                           |                |            |
| Pr <sup>3+</sup> -doped                               | 325         | 293-456     | 3866                   | 5557                 | 1.4374                    | 7997           | 10         |
| (K <sub>0.5</sub> Na <sub>0.5</sub> )NbO <sub>3</sub> |             |             |                        |                      |                           |                |            |
| Er3+: ZnO   | 532         | 83-493      | 819                    | 2394                 | 2.9230                    | 3445           | This work  |

**Table S3**. Comparison table for theoretical and experimental  $\Delta E$  ratio for various materials.

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